



Power Supply and TVT tests on DC/DC converter status report

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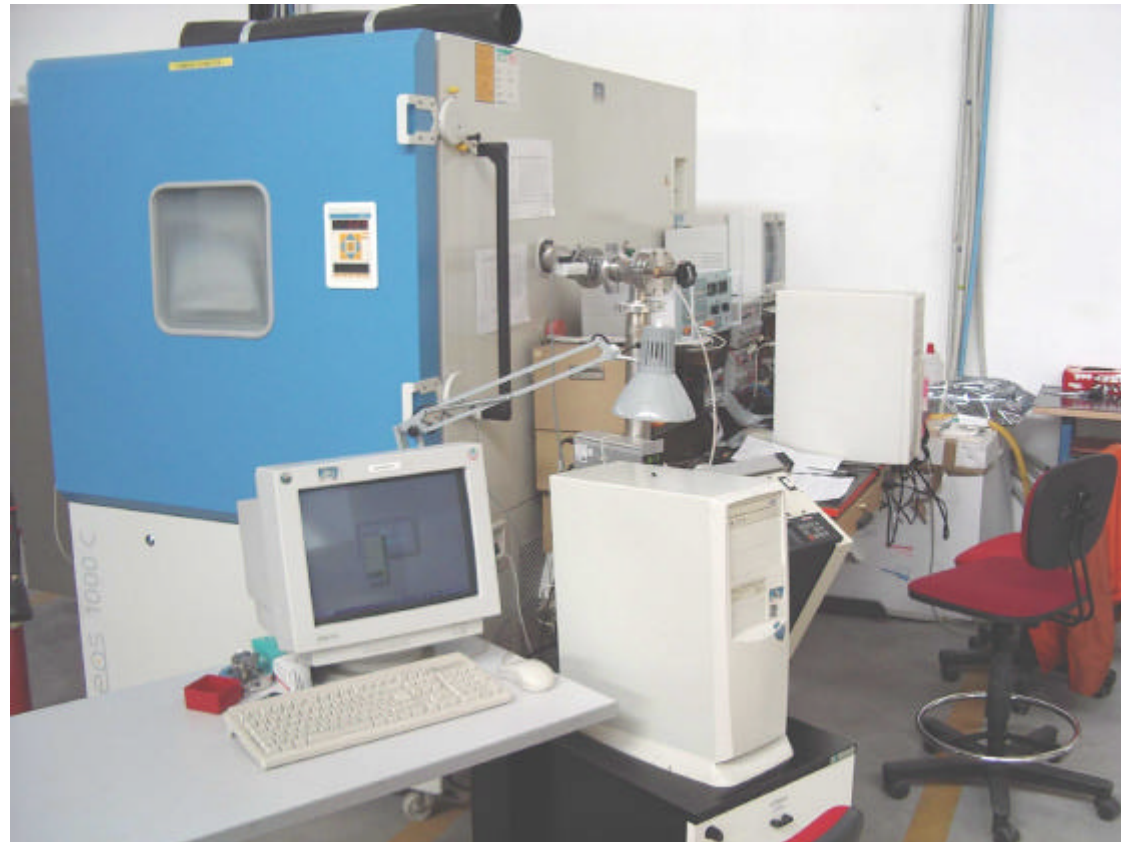
Summary

- ◆ TVT tests for DC/DC converters in Terni
- ◆ Production of ASI contract boards

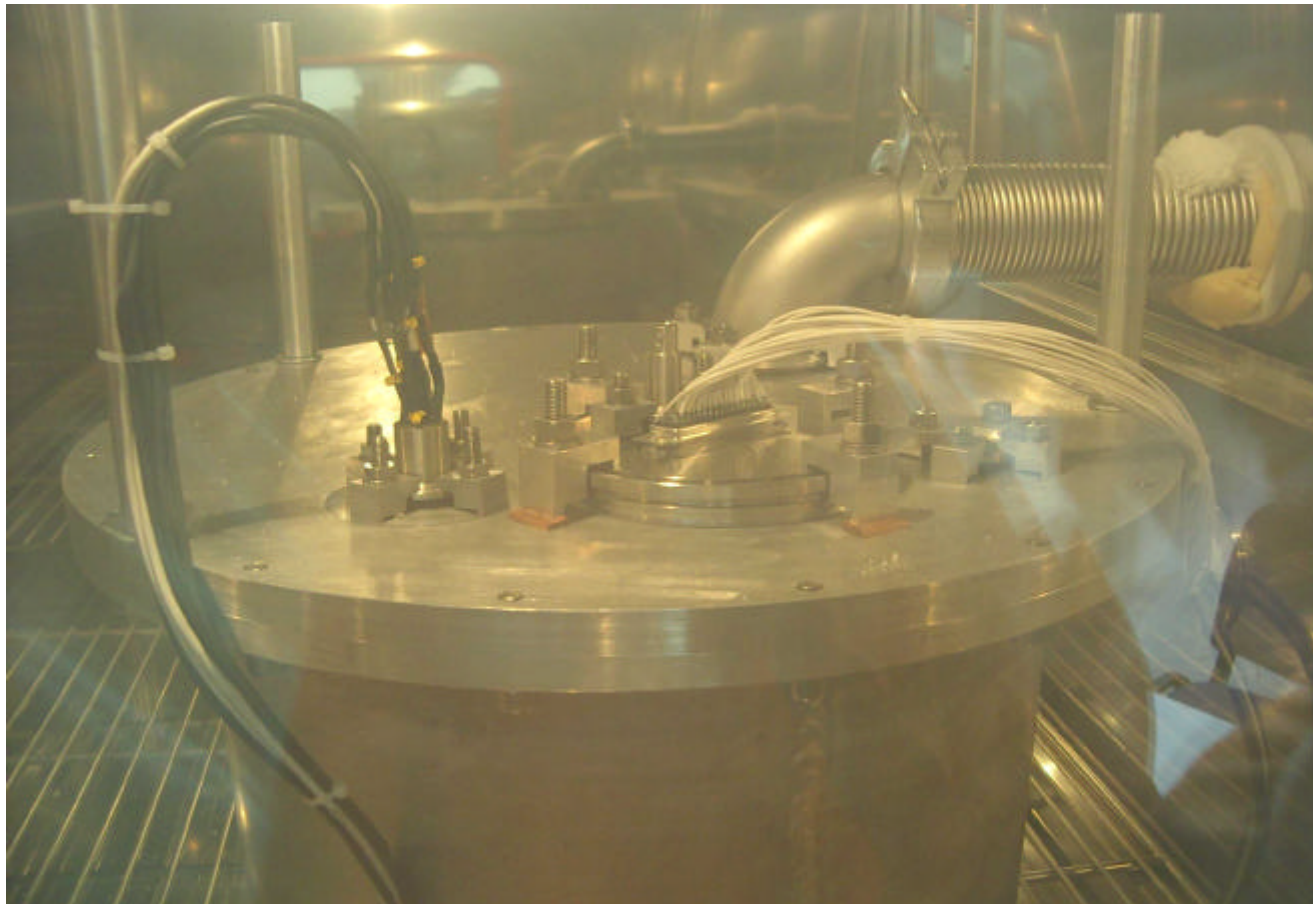
Purpose of the TVT test at single board level

- ◆ Give a reasonable thermal stress in vacuum to the card.
- ◆ Understand the thermal gradients on the board.
- ◆ Converters are tested to their typical current output value which is generally higher than nominal AMS current output.

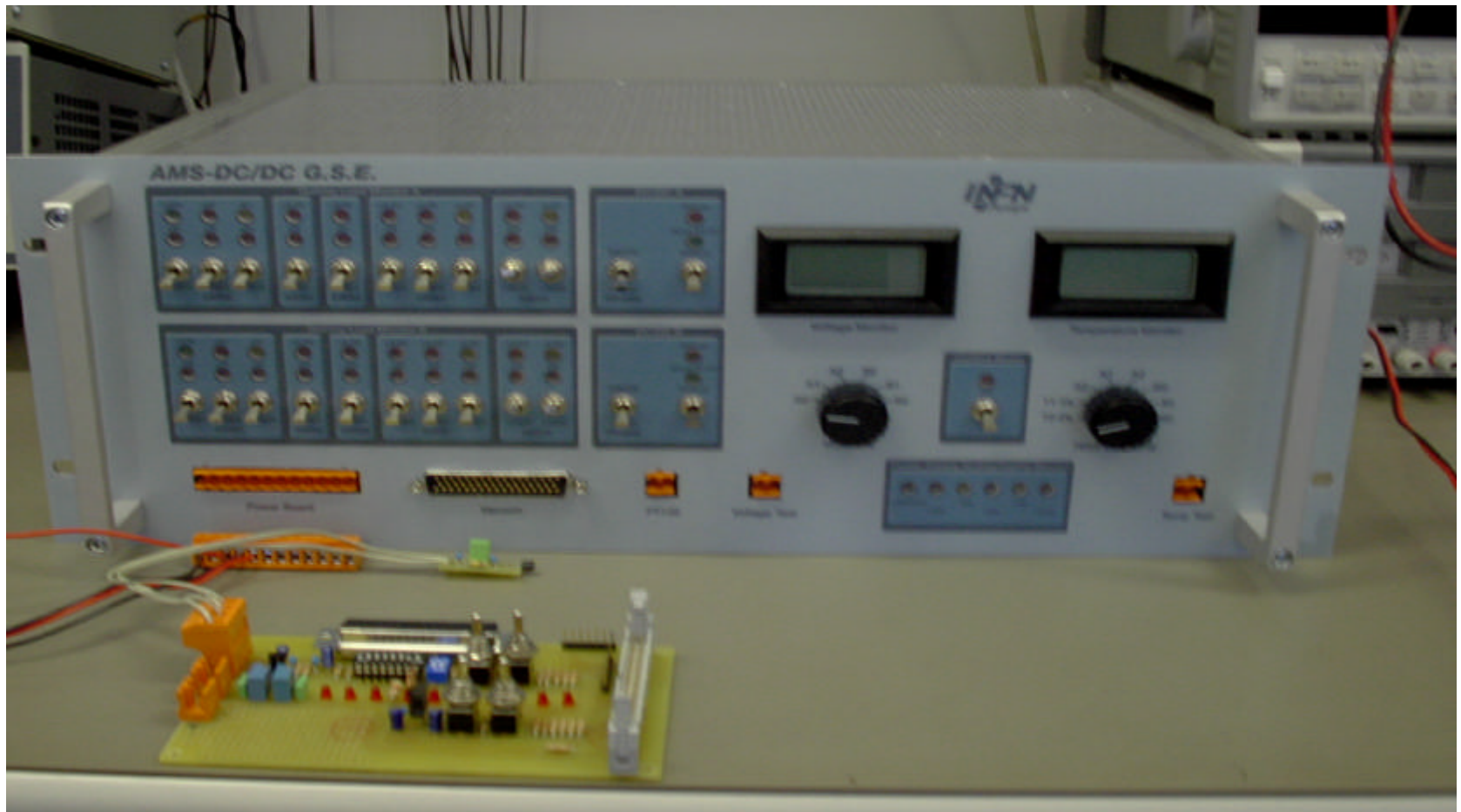
The test setup I



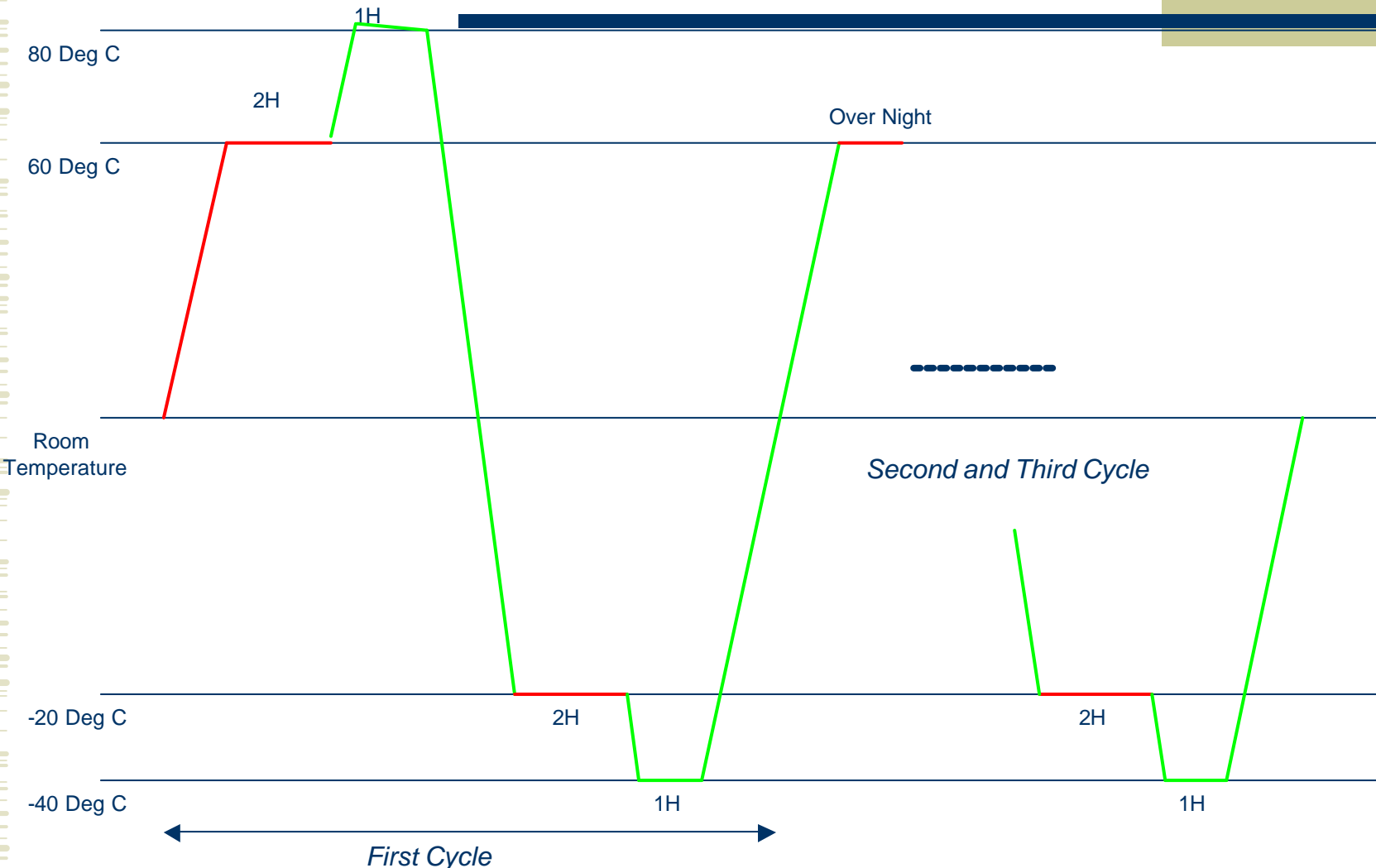
The test setup II



The test setup III



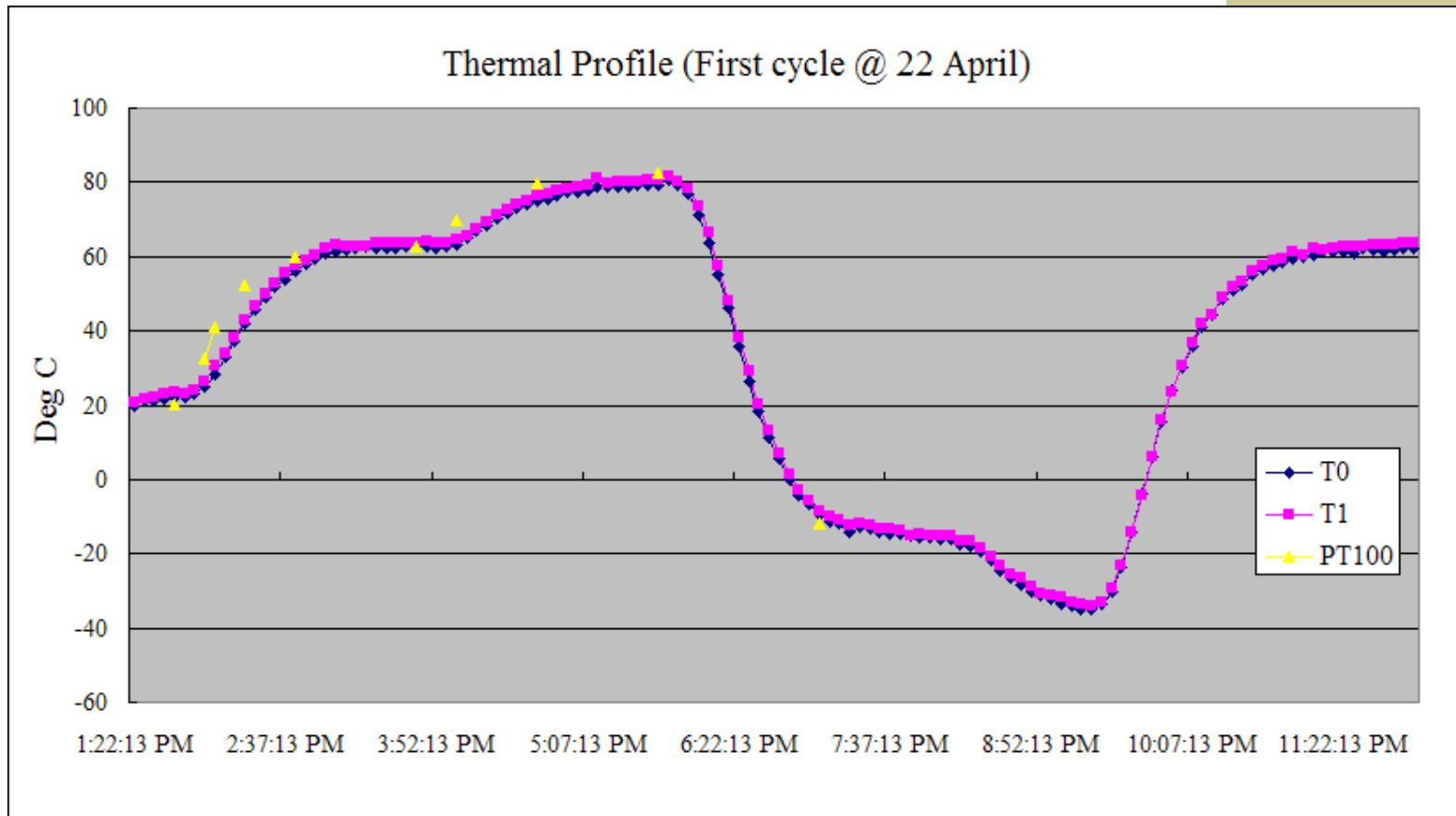
The TVT cycle



S9048 I

- ◆ First tested; procedure not strictly followed
- ◆ Side A on side B off
- ◆ Thermal sensors:
 - A0 Broken
 - A1 Switching MOSFET side B, lost during 2nd thermal cycle
 - A2 Rectifier MOSFET side B
 - B0 Transformer side A
 - B1 Rectifier MOSFET side A
 - B2 Switching MOSFET side A

S9048 raw data PT100 T0-T1 (first cycle)

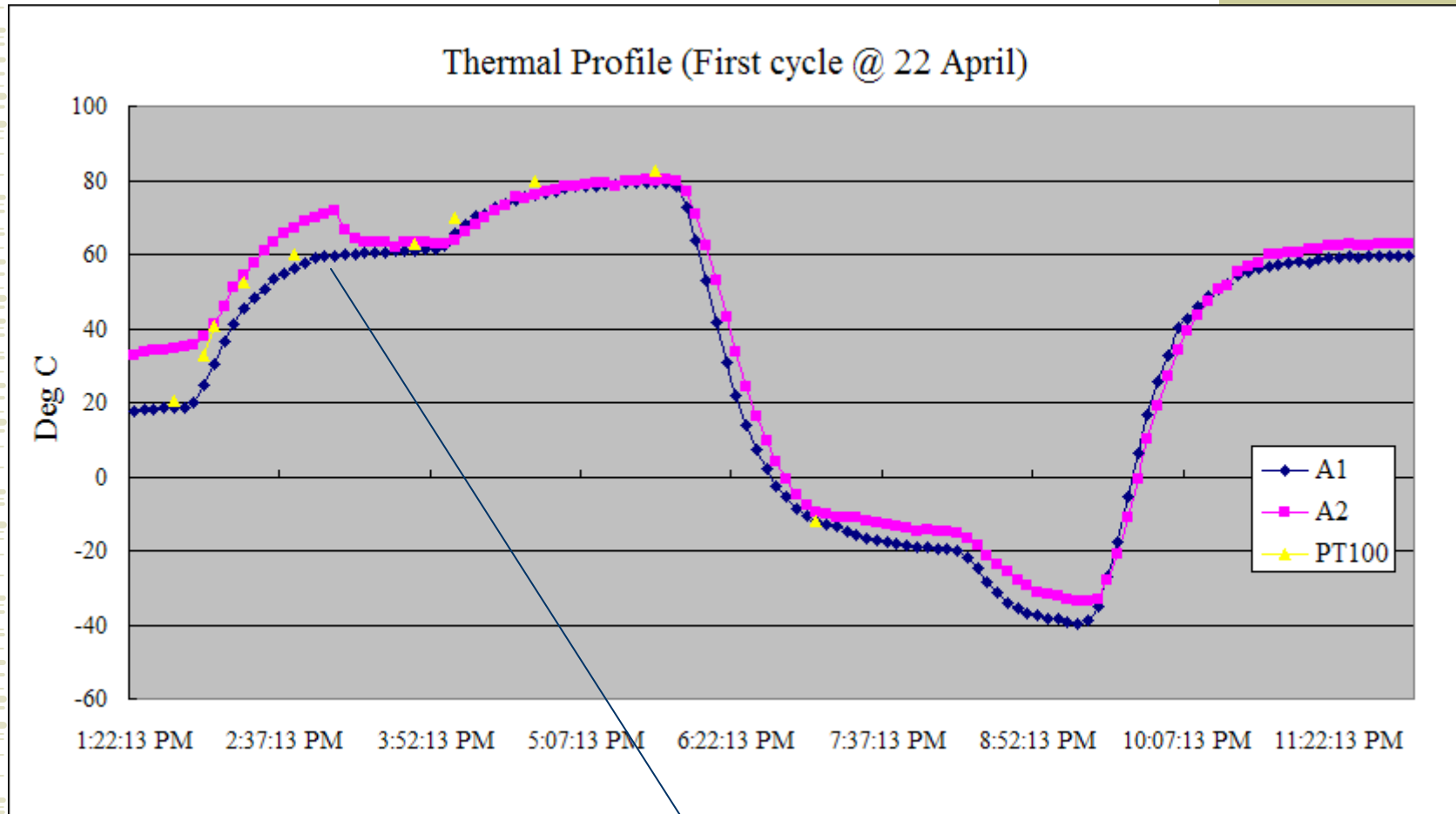


PT100: Sensor in the inner chamber

T0: Sensor 1, dissipation layer

T1: Sensor 2, dissipation layer

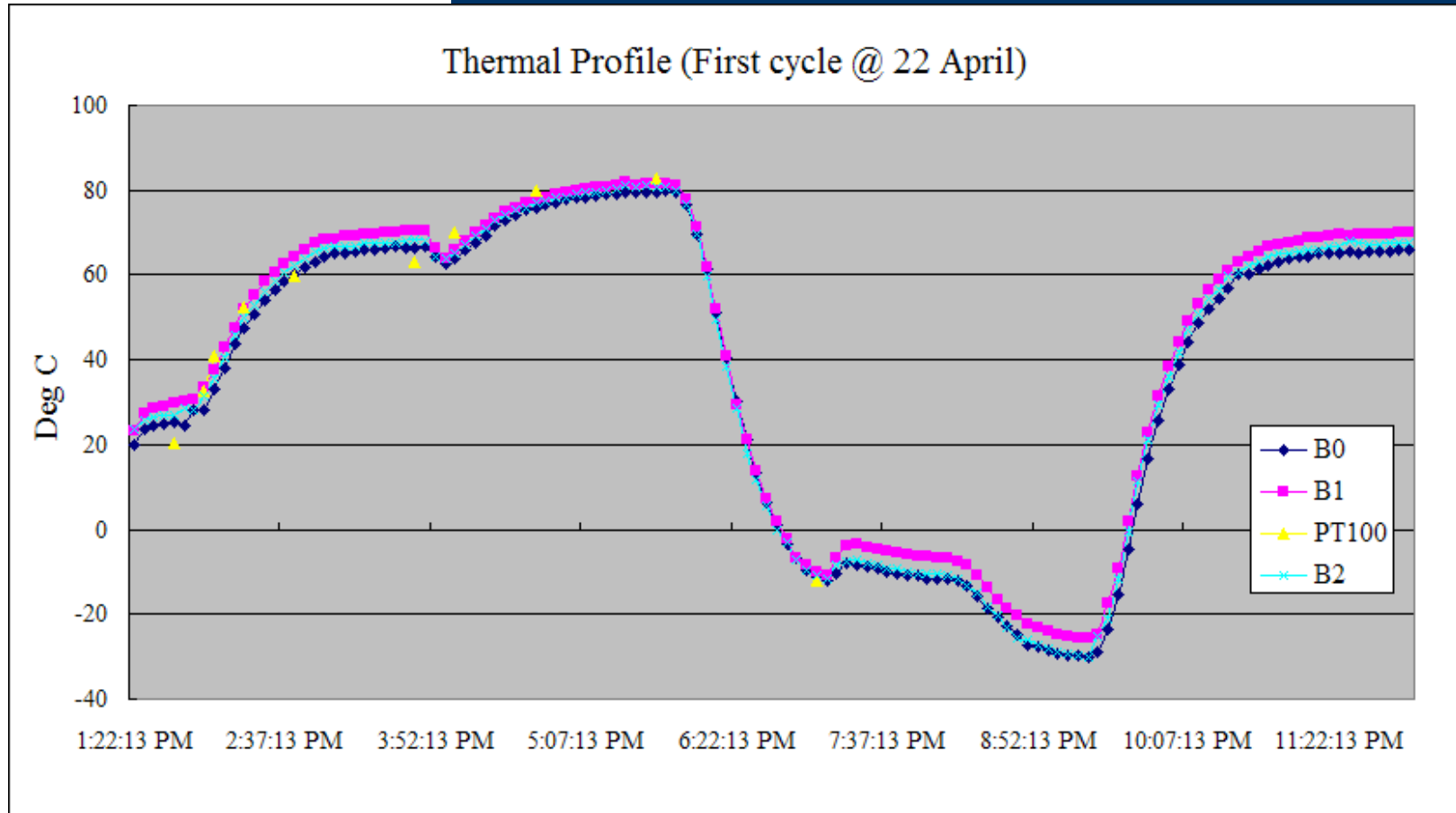
S9048 raw data PT100 A1 A2 (first cycle)



A1: Sensor 4 on MOS_Switch Side_B
A2: Sensor 5 on MOS_Rectifier Side_B

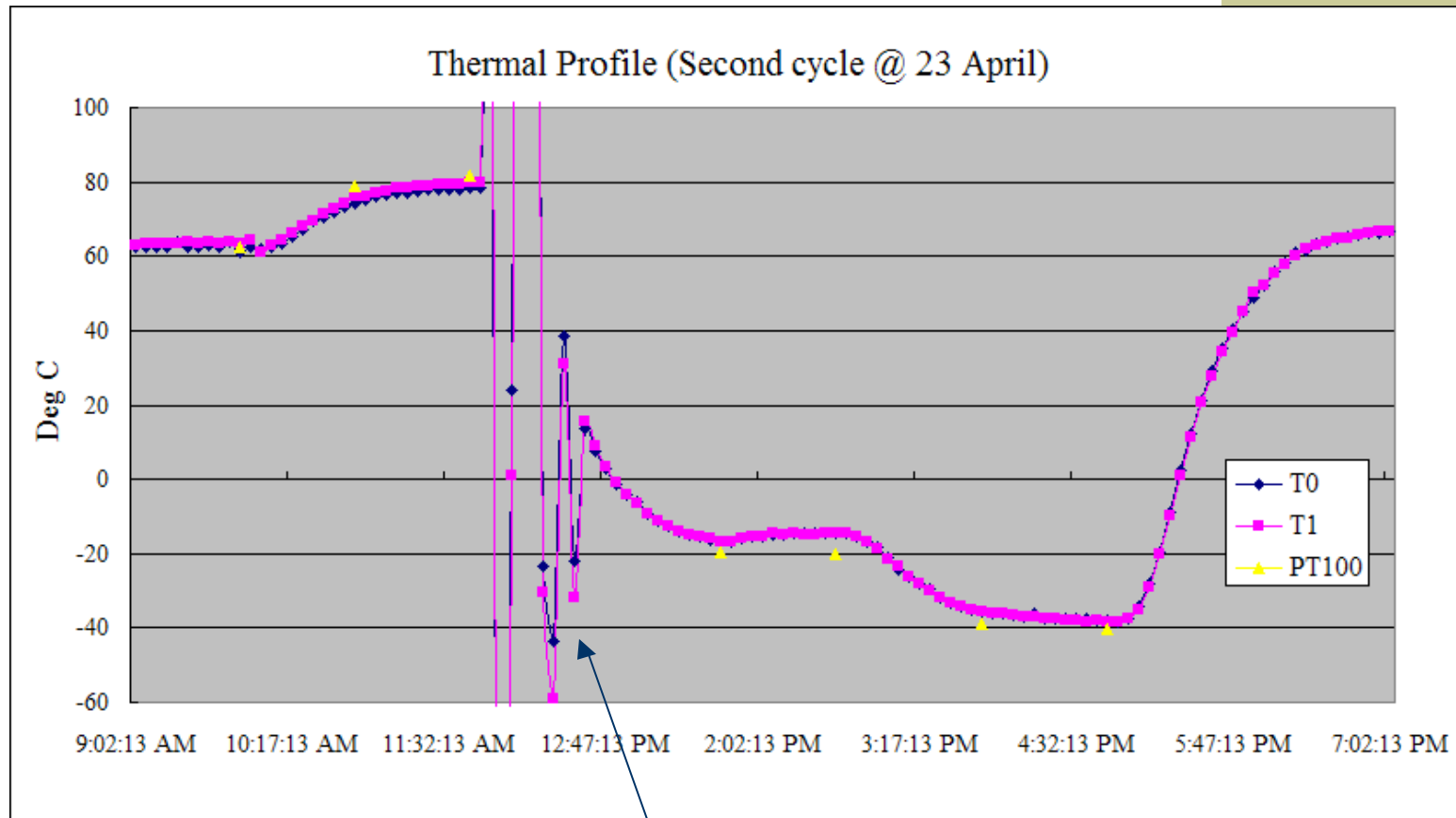
We did this wrong, we turn-on both side(A&B).
It should be turn-on only one side(A).

S9048 raw data PT100 B0 B1 B2 (first cycle)



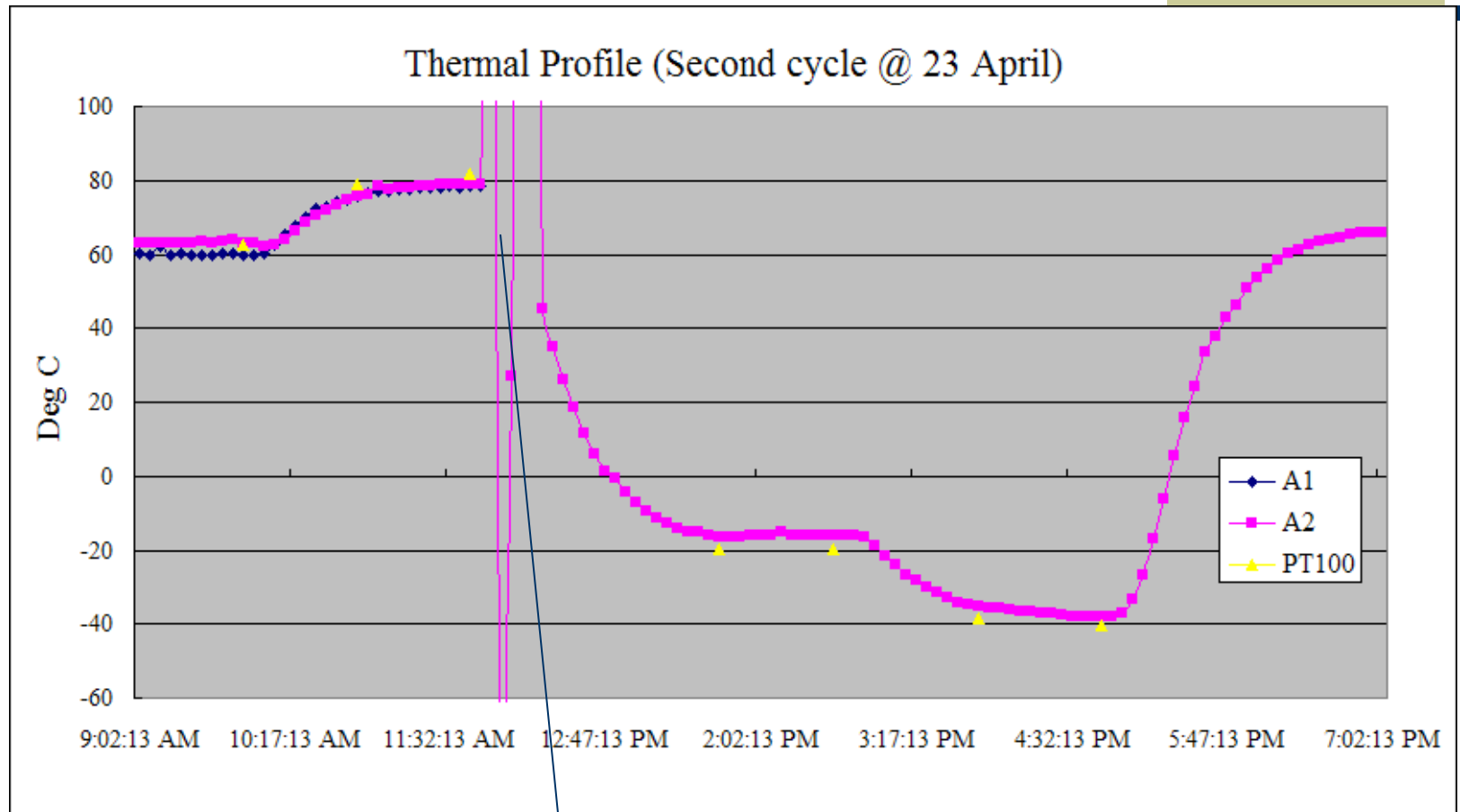
B0: Sensor 6 on Transformer Side_A
B1: Sensor 7 on MOS_Rectifier Side_A
B2: Sensor 8 on MOS_Switch Side_A

S9048 raw data PT100 T0-T1 (second cycle)



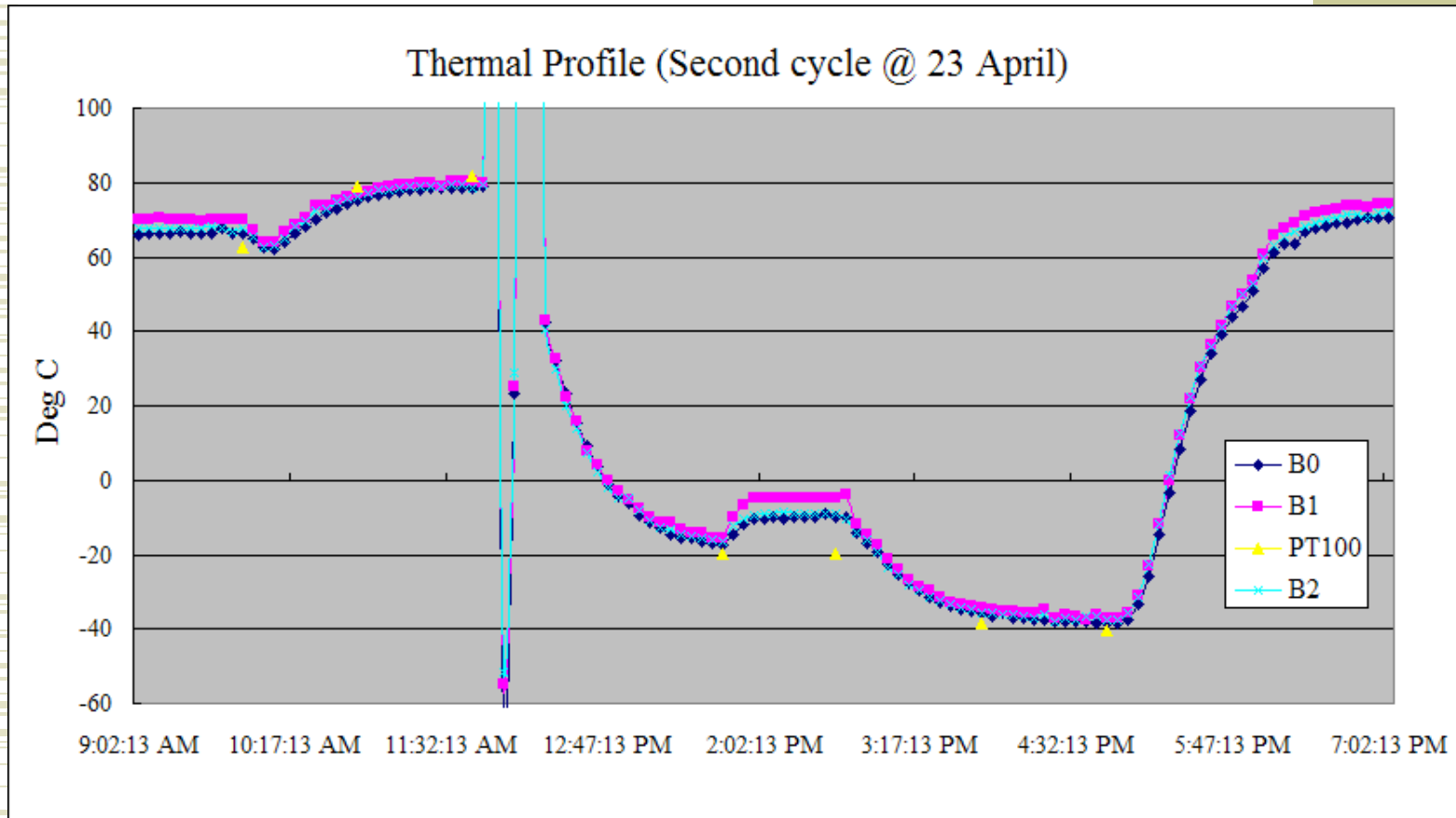
Temp Buffer(TL074) failed in this phase.

S9048 raw data PT100 A1 A2 (second cycle)



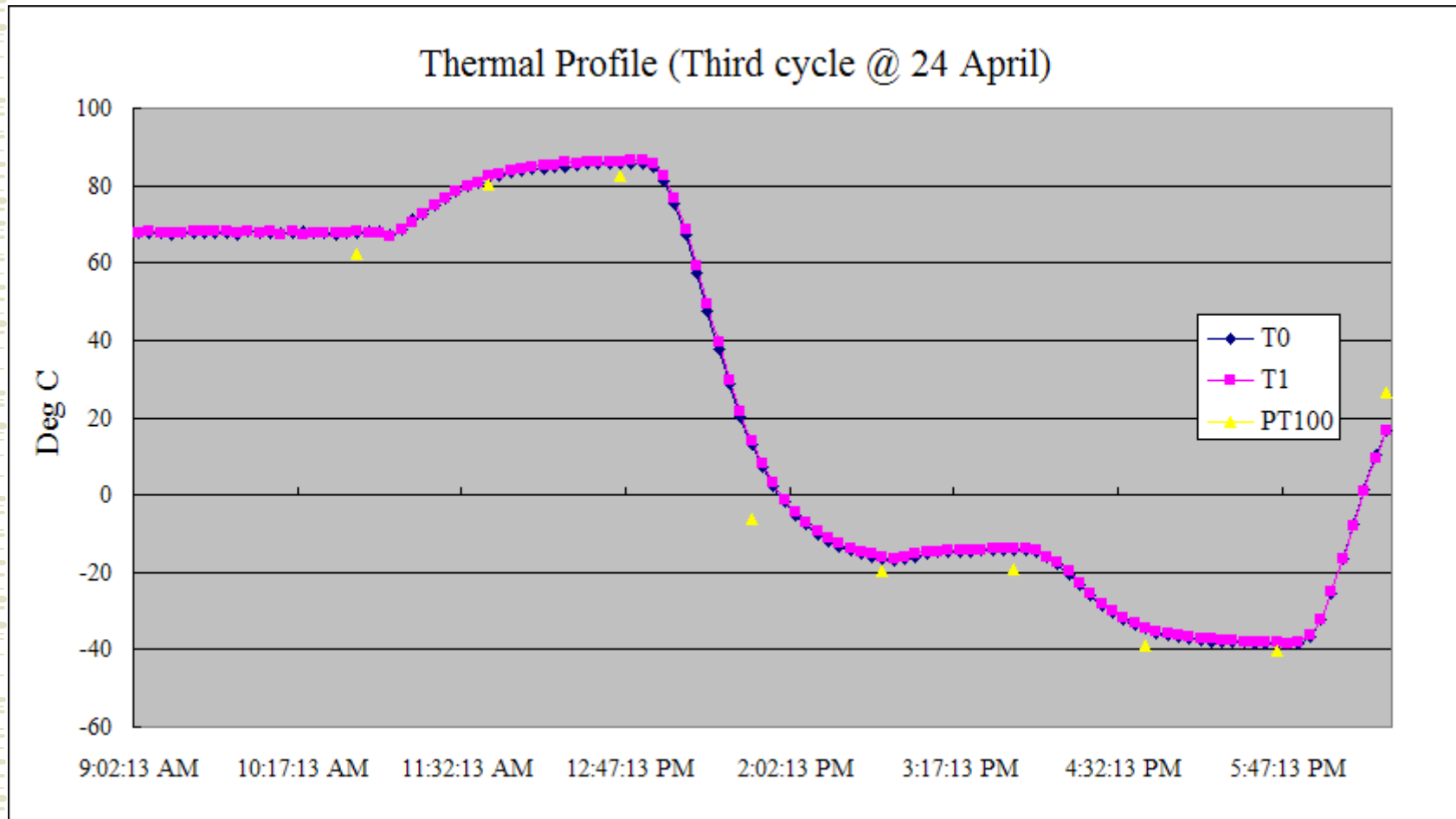
Lost A1 read-out after Temp. Buffer failed.

S9048 raw data PT100 B0 B1 B2 (second cycle)

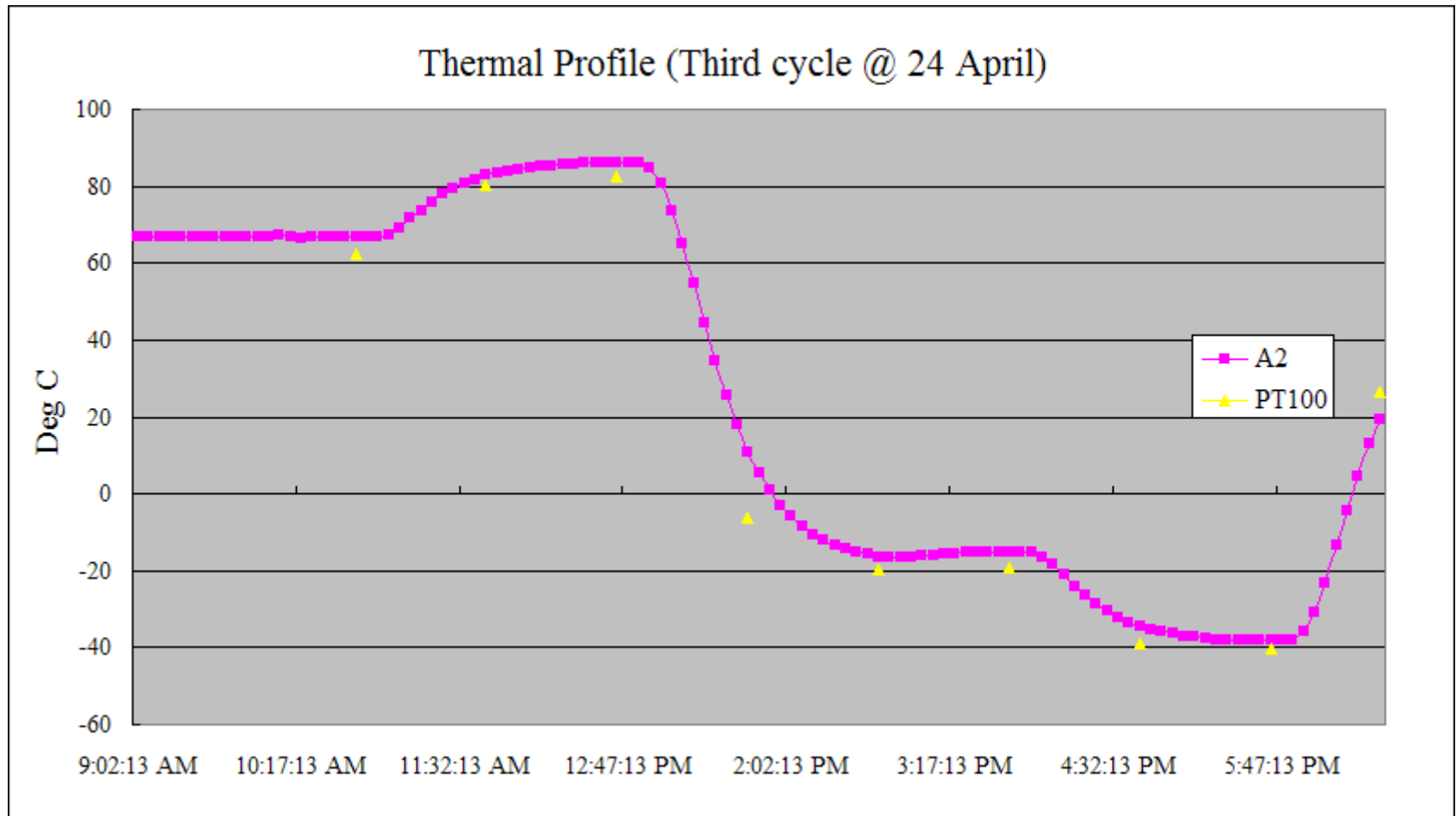


B0: Sensor 6 on Transformer Side_A
B1: Sensor 7 on MOS_Rectfier Side_A
B2: Sensor 8 on MOS_Switch Side_A

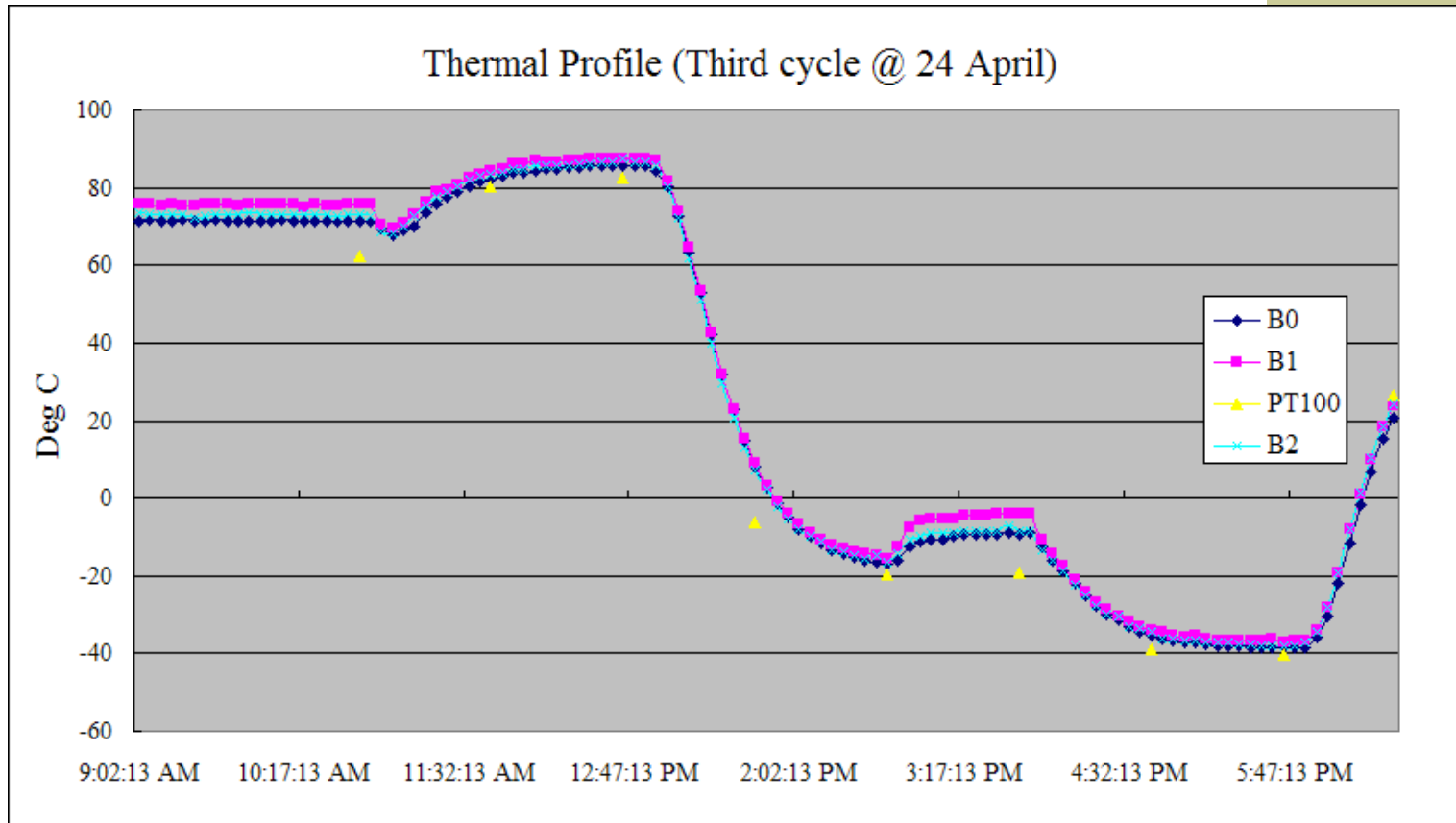
S9048 raw data PT100 T0-T1 (third cycle)



S9048 raw data PT100 A1 A2 (third cycle)



S9048 raw data PT100 B0 B1 B2 (third cycle)



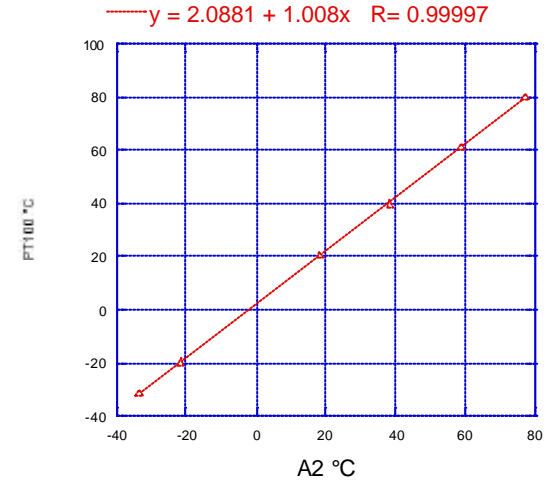
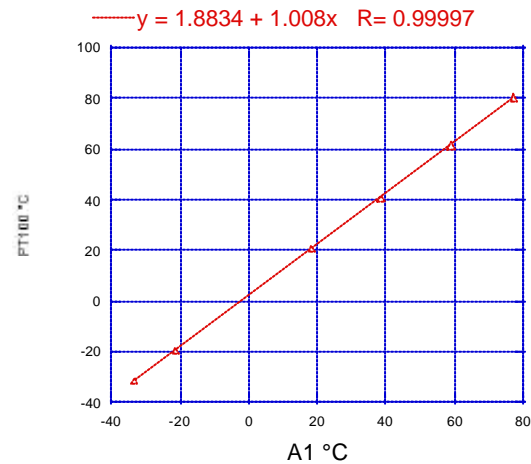
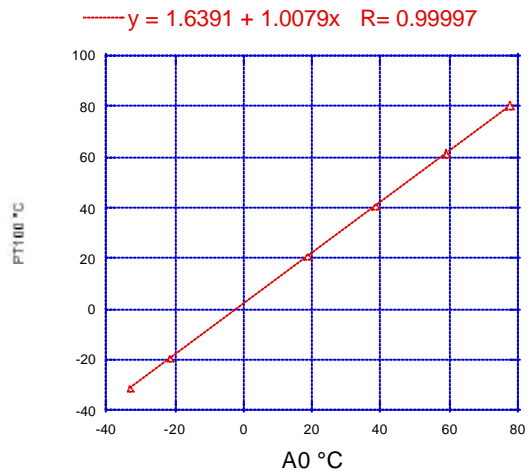
B0: Sensor 6 on Transformer Side_A
B1: Sensor 7 on MOS_Rectifier Side_A
B2: Sensor 8 on MOS_Switch Side_A



Interlude: The necessity of the calibration

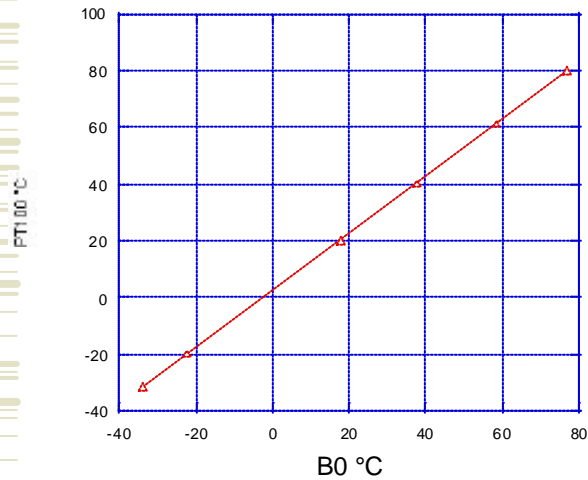
- ◆ LM35 sensor should be calibrated versus PT100
- ◆ Systematic current effect.

PT100-A0,A1,A2 first tests

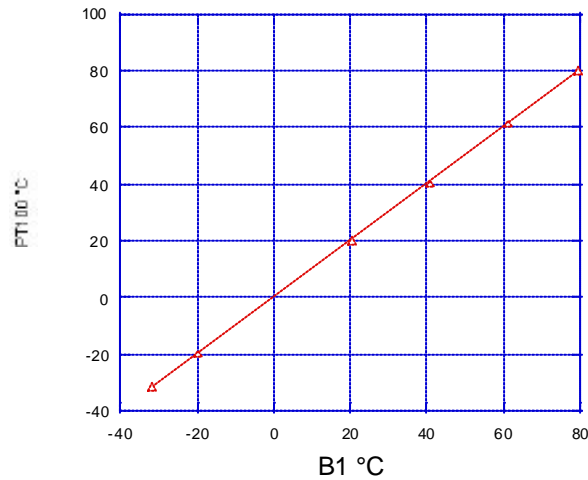


PT100-B0,B1,B2 first tests

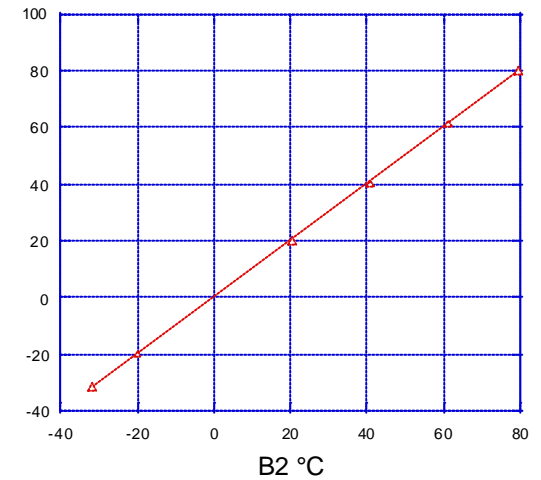
$$y = 2.5069 + 1.0095x \quad R = 0.99997$$



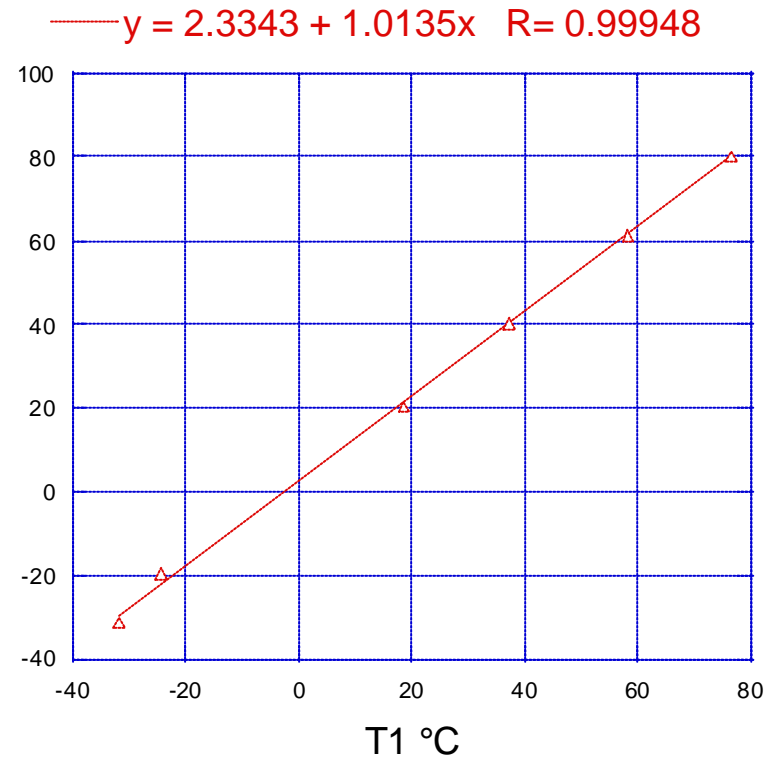
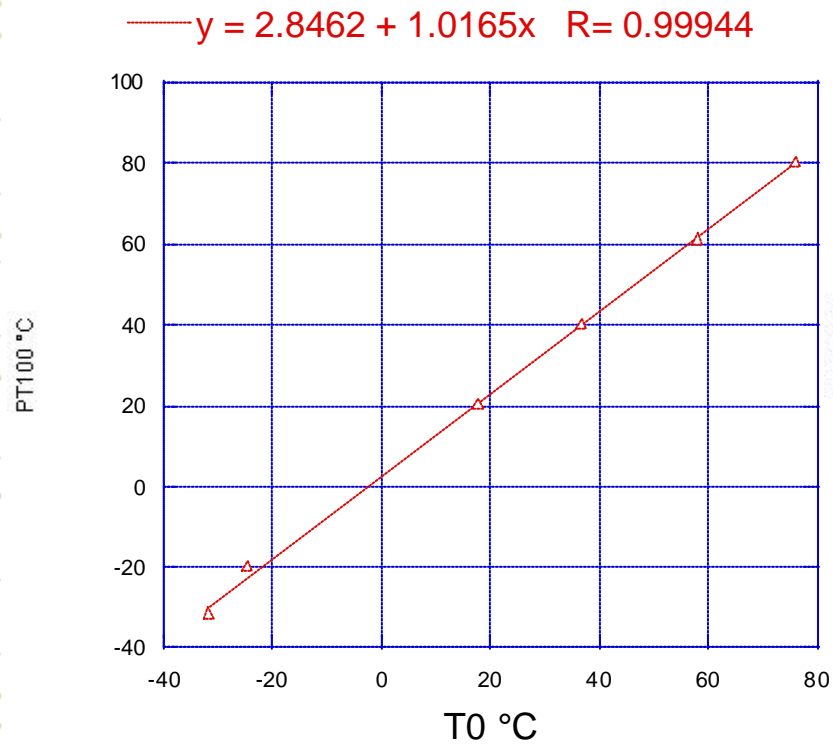
$$y = 0.037688 + 1.0031x \quad R = 0.99997$$



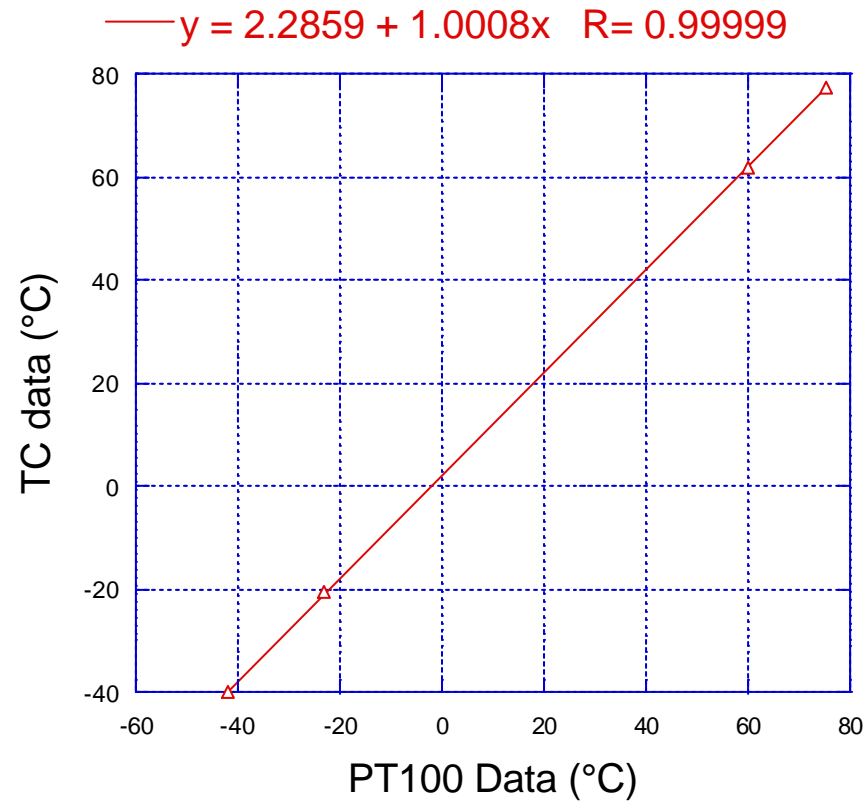
$$y = 0.19048 + 1.0019x \quad R = 0.99996$$



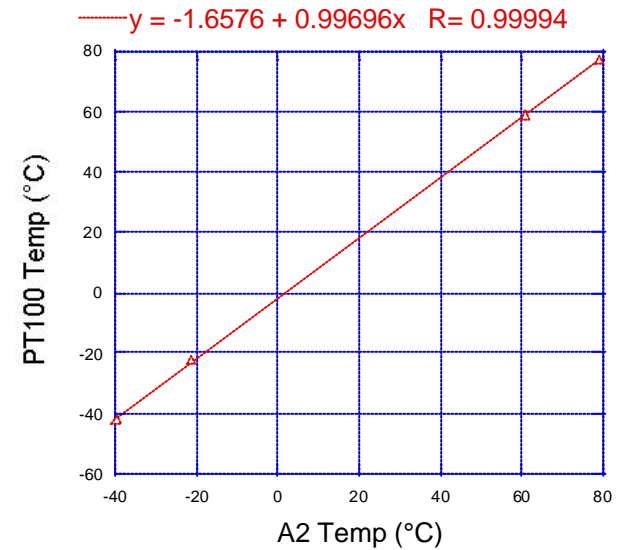
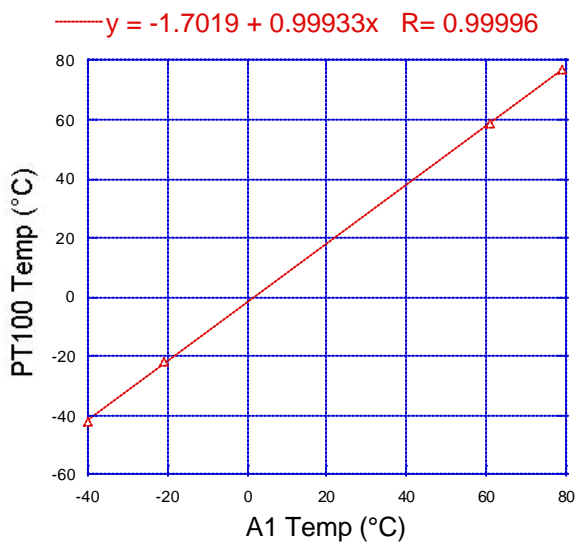
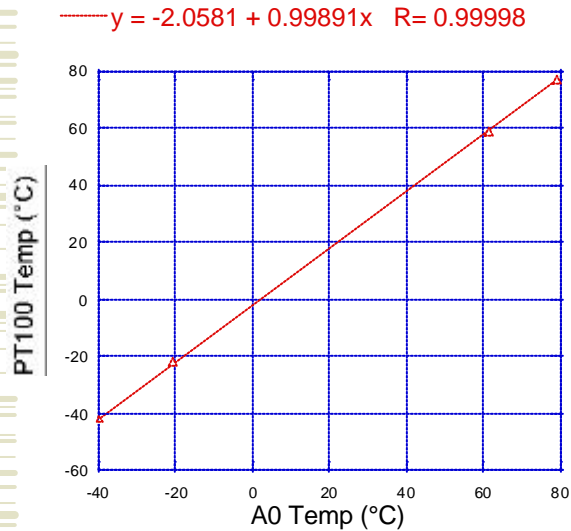
PT100-T0,T1 first tests



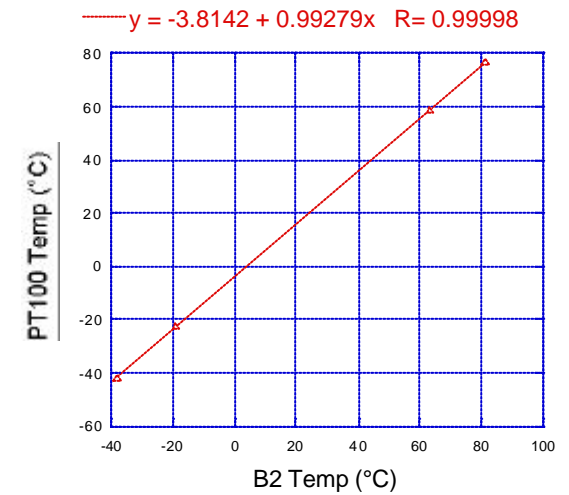
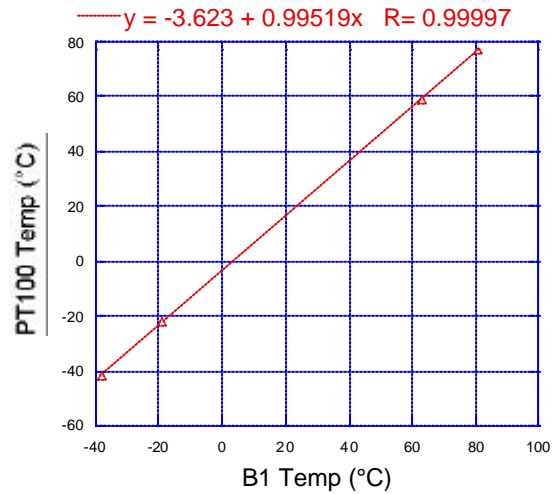
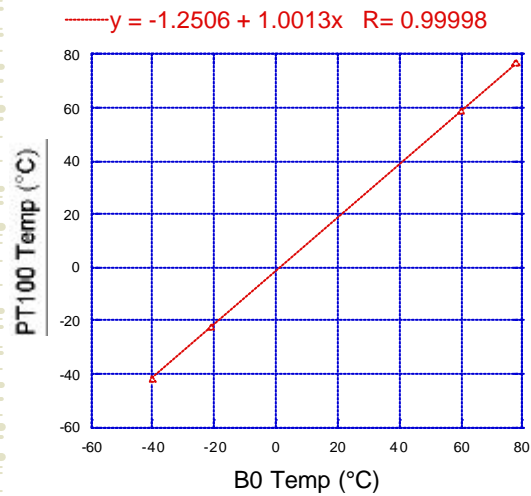
New PT100 TC test



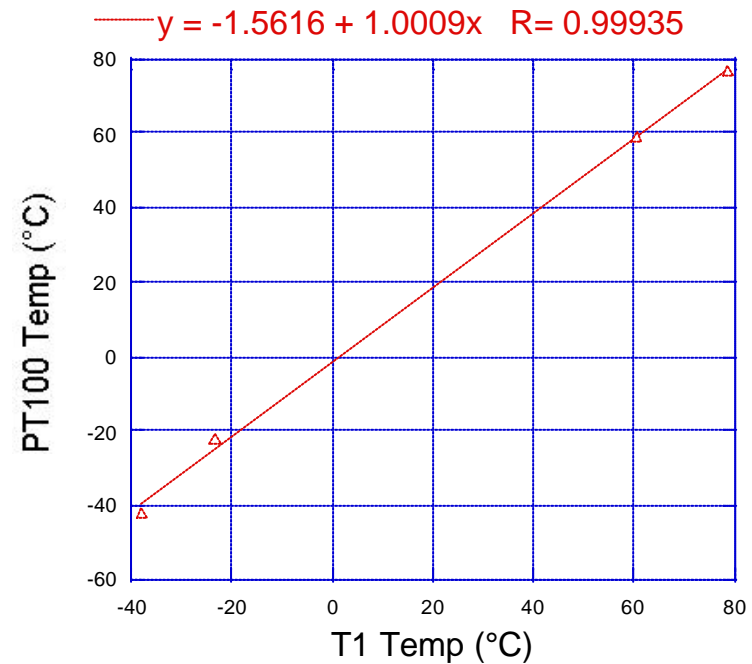
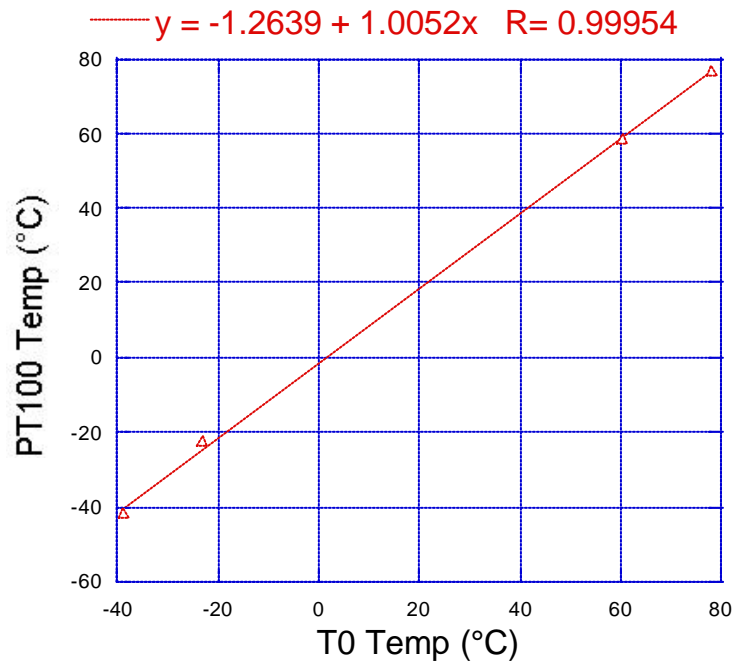
PT100-A0,A1,A2 second test



PT100-B0,B1,B2 second test



PT100-T0,T1 second test





Systematic current effect

- ◆ Due to current flowing on the ground on high current converters we noted a shift in the temperature measurement just after we turn off and on a converter.
- ◆ In order to avoid this we used temperature measurement before/after turn on or off to evaluate this effect.

Results on S9048

- ◆ S9048 had not functional problems during the test.
- ◆ We notice higher temperature on the transformer compared with the average value on the heat dissipation bar ($\Delta t=5.1^{\circ}\text{C}$ at 60°C and $\Delta t=7.1^{\circ}\text{C}$ at -20°C).
- ◆ We notice a small temperature increase on the rectifier MOSFET ($\Delta t=2.1^{\circ}\text{C}$ at 60°C and $\Delta t=3.2^{\circ}\text{C}$ at -20°C).
- ◆ We notice negligible increase on the off side on the switching MOSFET.

S9051 tests

- ◆ Both converters on
- ◆ Thermal sensors:
 - A0 Switching MOSFET side A
 - A1 Transormer side A
 - A2 Rectifier MOSFET side A
 - B0 Switching MOSFET side B
 - B1 Transormer side B
 - B2 Rectifier MOSFET side B

Results on the S9051

- ◆ S9051 had not functional problems during the test.
- ◆ Switching MOSFET temperature rise not very homogeneous ($\Delta t = 3.9\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 2.0\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side B, at $-20\text{ }^{\circ}\text{C}$ $\Delta t = 6.9\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 3.8\text{ }^{\circ}\text{C}$ on side B)
- ◆ Transformer temperature rise more homogeneous ($\Delta t = 3.5\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 3.7\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side B, at $-20\text{ }^{\circ}\text{C}$ $\Delta t = 6.7\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 4.8\text{ }^{\circ}\text{C}$ on side B)
- ◆ Rectifier MOSFET: $\Delta t = 3.4\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 2.1\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ on side B, at $-20\text{ }^{\circ}\text{C}$ $\Delta t = 7.1\text{ }^{\circ}\text{C}$ on side A and $\Delta t = 4.3\text{ }^{\circ}\text{C}$ on side B.

Tests on s9053

- ◆ One side on (B side) one side off
- ◆ Thermal sensors:
 - A0 Transformer side A
 - A1 output inductor side B
 - A2 MOSFET and freewheeling diode side A
 - B0 output inductor side A
 - B1 Transformer side B
 - B2 MOSFET and freewheeling diode side B

Results on s9053

- ◆ S9053 had not functional problems during the test.
- ◆ Output inductor hottest point: ($\Delta t = 6.0\text{ }^{\circ}\text{C}$ compared to the thermal bar at $60\text{ }^{\circ}\text{C}$ $\Delta t = 11.9\text{ }^{\circ}\text{C}$ at $-20\text{ }^{\circ}\text{C}$)
- ◆ Transformer: $\Delta t = 3.3\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ $\Delta t = 7.6\text{ }^{\circ}\text{C}$ at $-20\text{ }^{\circ}\text{C}$
- ◆ MOSFET and freewheeling diode: $\Delta t = 3.9\text{ }^{\circ}\text{C}$ at $60\text{ }^{\circ}\text{C}$ and $\Delta t = 9.2\text{ }^{\circ}\text{C}$ at $-20\text{ }^{\circ}\text{C}$
- ◆ Other sensors at the same level or slightly below thermal bar temperature

Tests on s9055

- ◆ One side on (A side) one side off
- ◆ Thermal sensor
 - A0 Trasformer side A
 - A1 MOSFET side A
 - A2 vacuum case
 - B0 Trasformer side B
 - B1 MOSFET side B
 - B2 vacuum case

Results on S9055

- ◆ S9055 had not functional problems during test
- ◆ Trasformer: $\Delta t = 0.9 \text{ }^{\circ}\text{C}$ @ $60 \text{ }^{\circ}\text{C}$, $\Delta t = 1.8 \text{ }^{\circ}\text{C}$ @ $-20 \text{ }^{\circ}\text{C}$
- ◆ MOSFET: $\Delta t = 2.6 \text{ }^{\circ}\text{C}$ @ $60 \text{ }^{\circ}\text{C}$, $\Delta t = 4.5 \text{ }^{\circ}\text{C}$ @ $-20 \text{ }^{\circ}\text{C}$
- ◆ Other sensors at the same level or slightly below thermal bar temperature



Test of S9054

- ◆ No converter failed during this test
- ◆ Data not yet available for this presentation

Conclusions on TVT test

- ◆ No converter failed during test.
- ◆ The results are reproducible in terms of cycles at level $< 1\text{ }^{\circ}\text{C}$
- ◆ The results are not the same for A and B
- ◆ The measured values of Δt are not the same at the two test temperature ($60\text{ }^{\circ}\text{C}$ and $-20\text{ }^{\circ}\text{C}$).
- ◆ The temperature mapping information we obtained are not too accurate but give reasonable results

ASI contract board production

- ◆ TPD controller: PCB under preparation at the moment CAEN has no component. Ready by mid-october (?).
- ◆ TPD filter: design finished PCB ready by mid-october. Ready by end October.
- ◆ TPSFE: Master ready PCB finished by early september. Ready by end October
- ◆ TBS: design starts at september. Ready by december.
- ◆ TBP: ready